

FNΠ

2

NC – No

V+[]3

#### FEATURES

- **RS-232 Bus-Pin ESD Protection Exceeds** ±15 kV Using Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V<sub>CC</sub> Supply .
- Operates up to 250 kbit/s •
- Two Drivers and Two Receivers .
- Low Standby Current . . . 1 µA Typical
- External Capacitors . . .  $4 \times 0.1 \ \mu F$ •
- Accepts 5-V Logic Input With 3.3-V Supply
- Alternative High-Speed Pin-Compatible Device (1 Mbit/s)
  - TRSF3222

#### APPLICATIONS

- **Battery-Powered Systems** •
- **PDAs** •
- Notebooks
- Laptops
- Palmtop PCs •
- **Hand-Held Equipment**

#### DESCRIPTION/ORDERING INFORMATION

The TRS3222 consists of two line drivers, two line receivers, and a dual charge-pump circuit with ±15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. The device operates at data signaling rates up to 250 kbit/s and a maximum of 30-V/us driver output slew rate.

The TRS3222 can be placed in the power-down mode by setting PWRDOWN low, which draws only 1 µA from the power supply. When the device is powered down, the receivers remain active while the drivers are placed in the high-impedance state. Also, during power down, the onboard charge pump is disabled; V+ is lowered to  $V_{CC}$ , and V- is raised toward GND. Receiver outputs also can be placed in the high-impedance state by setting EN high.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

C1-[	4	17	] DOUT1
C1-[ C2+[	5	16	] RIN1
C2-[	6	15	] ROUT1
V-[	7	14	] NC
DOUT2[	8	13	] DIN1
RIN2	9	12	] DIN2
ROUT2	10	11	] NC
- No interr	nal conne	ectio	n

20 PWRDOWN

19 🛛 V<sub>CC</sub>

18 GND

DB, DW, OR PW PACKAGE

(TOP VIEW)

# TRS3222 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH $\pm 15\text{-kV}$ ESD PROTECTION



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#### **ORDERING INFORMATION**

T <sub>A</sub>	PAC	KAGE <sup>(1)(2)</sup>	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube of 25	TRS3222CDW	- TRS3222C
	3010 - 010	Reel of 2000	TRS3222CDWR	1K332220
0°C to 70°C	SSOP – DB	Tube of 70	TRS3222CDB	DEDDC
0°C to 70°C	550P - DB	Reel of 2000	TRS3222CDBR	RS22C
	TSSOP – PW	Tube of 70	TRS3222CPW	- RS22C
	1330P - PW	Reel of 2000	TRS3222CPWR	- K322C
	SOIC - DW	Tube of 25	TRS3222IDW	- TRS3222I
	50IC - DW	SSOP – DB	TRS3222IDWR	- 18332221
4000 to 0500		Tube of 70	TRS3222IDB	DCOOL
–40°C to 85°C	SSOP – DB	Reel of 2000	TRS3222IDBR	- RS22I
		Tube of 70	TRS3222IPW	- RS22I
	TSSOP – PW	Reel of 2000	TRS3222IPWR	ROZZI

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

## **FUNCTION TABLES**

#### Each Driver<sup>(1)</sup>

INPUTS		OUTPUT
DIN	PWRDOWN	DOUT
Х	L	Z
L	Н	Н
Н	Н	L

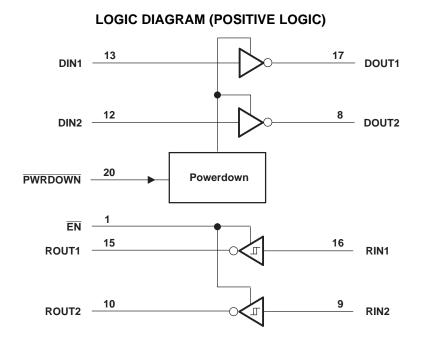
(1) H = high level, L = low level, X = irrelevant, Z = high impedance

#### Each Receiver<sup>(1)</sup>

INPUTS		OUTPUT
RIN	EN	ROUT
L	L	Н
н	L	L
Х	н	Z
Open	L	Н

 H = high level, L = low level, X = irrelevant, Z = high impedance (off), Open = input disconnected or connected driver off

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# **TRS3222** 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

SLLS815-JULY 2007

#### Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range <sup>(2)</sup>		-0.3	6	V
V+	Positive output supply voltage range <sup>(2)</sup>		-0.3	7	V
V–	Negative output supply voltage range <sup>(2</sup>	2)	0.3	-7	V
V+ - V-	Supply voltage difference <sup>(2)</sup>			13	V
M		Drivers, EN, PWRDOWN	-0.3	6	N/
VI	Input voltage range	Receivers	-25	25	V
N/		Drivers	-13.2	13.2	N/
Vo	Output voltage range	Receivers	-0.3	V <sub>CC</sub> + 0.3	V
		DB package		70	
$\theta_{JA}$	Package thermal impedance (3) (4)	DW package		58	°C/W
		PW package		83	
TJ	Operating virtual junction temperature			150	°C
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to network GND.

(3) Maximum power dissipation is a function of  $T_J(max)$ ,  $\theta_{JA}$ , and  $T_A$ . The maximum allowable power dissipation at any allowable ambient temperature is  $P_D = (T_J(max) - T_A)/\theta_{JA}$ . Operating at the absolute maximum  $T_J$  of 150°C can affect reliability.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

## **Recommended Operating Conditions**<sup>(1)</sup>

#### See Figure 5

				MIN	NOM	MAX	UNIT
	Supply voltage	$V_{CC} = 3.3 V$		3	3.3	3.6	V
	Supply voltage	$V_{CC} = 5 V$		4.5	5	5.5	v
v	Driver and control high level input voltage	and control high-level input voltage DIN, EN, PWRDOWN	$V_{CC} = 3.3 V$	2			V
VIH	Driver and control high-level input voltage		$V_{CC} = 5 V$	2.4			v
$V_{\text{IL}}$	Driver and control low-level input voltage	DIN, EN, PWRDOWN				0.8	V
$V_{I}$	Driver and control input voltage	DIN, EN, PWRDOWN		0		5.5	V
$V_{I}$	Receiver input voltage			-25		25	V
т	Operating free-air temperature	TRS222C		0		70	°C
T <sub>A</sub>		TRS222I		-40		85	C

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

#### Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
I <sub>I</sub>	Input leakage current (EN, PWRDOWN)			±0.01	±1	μA
	Supply current	No load, PWRDOWN at V <sub>CC</sub>		0.3	1	mA
ICC	Supply current (powered off)	No load, PWRDOWN at GND		1	10	μA

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

## **DRIVER SECTION**

## Electrical Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS		MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	5.4		V
V <sub>OL</sub>	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to GND,	$DIN = V_{CC}$	-5	-5.4		V
I <sub>IH</sub>	High-level input current	$V_{I} = V_{CC}$			±0.01	±1	μA
I <sub>IL</sub>	Low-level input current	V <sub>I</sub> at GND			±0.01	±1	μA
	Short-circuit output current <sup>(3)</sup>	V <sub>CC</sub> = 3.6 V,	$V_0 = 0 V$		105	100	
I <sub>OS</sub>	Short-circuit output current	V <sub>CC</sub> = 5.5 V,	$V_0 = 0 V$	-	±35	±60	mA
r <sub>o</sub>	Output resistance	$V_{CC}$ , V+, and V– = 0 V,	$V_0 = \pm 2 V$	300	10 M		Ω
	Output leakage current	$\frac{PWRDOWN}{V_{CC}} = GND,$ $V_{CC} = 3 V \text{ to } 3.6 V$	V <sub>O</sub> = ±12 V			±25	
l <sub>off</sub>		$\frac{PWRDOWN}{V_{CC}} = GND,$ V <sub>CC</sub> = 4.5 V to 5.5 V	V <sub>O</sub> = ±10 V			±25	μA

 Test conditions are C1–C4 = 0.1 μF at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047 μF, C2–C4 = 0.33 μF at V<sub>CC</sub> = 5 V ± 0.5 V.
 All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.
 Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one extended by a based of the time. output should be shorted at a time.

## Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CO	TEST CONDITIONS		TYP <sup>(2)</sup>	MAX	UNIT
	Maximum data rate	C <sub>L</sub> = 1000 pF, One DOUT switching,	R <sub>L</sub> = 3 kΩ, See Figure 1	150	250		kbit/s
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	$C_L$ = 150 pF to 2500 pF, See Figure 2	$R_L = 3 \ k\Omega$ to 7 k $\Omega$ ,		300		ns
SR(tr)	Slew rate, transition region	$R_L = 3 k\Omega$ to 7 k $\Omega$ ,	$C_{L} = 150 \text{ pF} \text{ to } 1000 \text{ pF}$	6		30	V/µs
SR(II)	(see Figure 1)	$V_{CC} = 3.3 V$	$C_{L} = 150 \text{ pF} \text{ to } 2500 \text{ pF}$	4		30	v/µs

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V.

(2) All typical values are at  $V_{CC} = 3.3$  V or  $V_{CC} = 5$  V, and  $T_A = 25^{\circ}$ C. (3) Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device.

# **TRS3222** 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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#### **RECEIVER SECTION**

## **Electrical Characteristics**<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP <sup>(2)</sup>	MAX	UNIT
V <sub>OH</sub>	High-level output voltage	$I_{OH} = -1 \text{ mA}$	V <sub>CC</sub> – 0.6	V <sub>CC</sub> – 0.1		V
V <sub>OL</sub>	Low-level output voltage	I <sub>OH</sub> = 1.6 mA			0.4	V
V <sub>IT+</sub> Positive-going input threshold voltage	$V_{CC} = 3.3 V$		1.5	2.4	V	
	Positive-going input threshold voltage	$V_{CC} = 5 V$		1.8	2.4	v
V	Negative-going input threshold voltage	$V_{CC} = 3.3 V$	0.6	1.2		V
V <sub>IT-</sub>		$V_{CC} = 5 V$	0.8	1.5		v
V <sub>hys</sub>	Input hysteresis (V <sub>IT+</sub> – V <sub>IT-</sub> )			0.3		V
I <sub>off</sub>	Output leakage current	$\overline{EN} = V_{CC}$		±0.05	±10	μA
r <sub>l</sub>	Input resistance	$V_1 = \pm 3 V$ to $\pm 25 V$	3	5	7	kΩ

(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C.

(2)

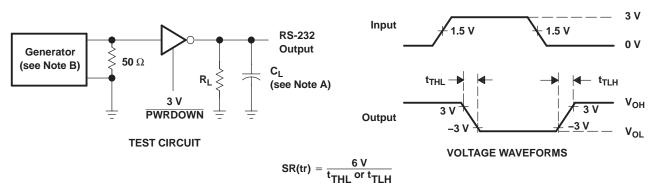
#### Switching Characteristics<sup>(1)</sup>

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN TYP <sup>(2)</sup> MAX	UNIT
t <sub>PLH</sub>	Propagation delay time, low- to high-level output	$C_L = 150 \text{ pF}$ , See Figure 3	300	ns
t <sub>PHL</sub>	Propagation delay time, high- to low-level output	$C_L = 150 \text{ pF}$ , See Figure 3	300	ns
t <sub>en</sub>	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega,$ See Figure 4	200	ns
t <sub>dis</sub>	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega,$ See Figure 4	200	ns
t <sub>sk(p)</sub>	Pulse skew <sup>(3)</sup>	See Figure 3	300	ns

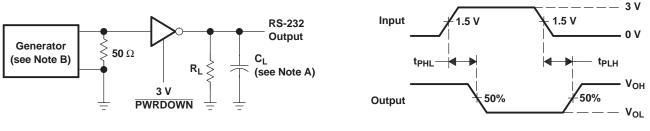
(1) Test conditions are C1–C4 = 0.1  $\mu$ F at V<sub>CC</sub> = 3.3 V ± 0.3 V; C1 = 0.047  $\mu$ F, C2–C4 = 0.33  $\mu$ F at V<sub>CC</sub> = 5 V ± 0.5 V. (2) All typical values are at V<sub>CC</sub> = 3.3 V or V<sub>CC</sub> = 5 V, and T<sub>A</sub> = 25°C. (3) Pulse skew is defined as  $|t_{PLH} - t_{PHL}|$  of each channel of the same device.

#### PARAMETER MEASUREMENT INFORMATION



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_0$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.

#### Figure 1. Driver Slew Rate

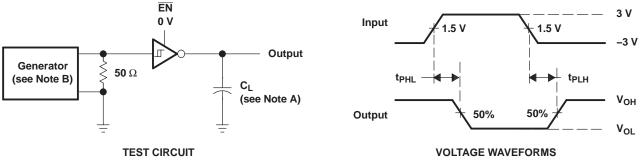


#### **TEST CIRCUIT**

**VOLTAGE WAVEFORMS** 

- A.  $C_L$  includes probe and jig capacitance.
- B. The pulse generator has the following characteristics: PRR = 250 kbit/s,  $Z_0$  = 50  $\Omega$ , 50% duty cycle,  $t_r \le 10$  ns,  $t_f \le 10$  ns.





A. C<sub>L</sub> includes probe and jig capacitance.

B. The pulse generator has the following characteristics:  $Z_O = 50 \ \Omega$ , 50% duty cycle,  $t_r \le 10 \text{ ns}$ .

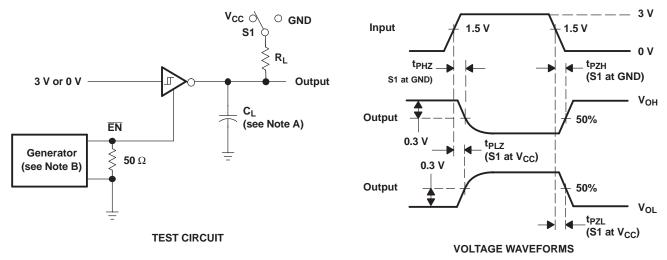
**Figure 3. Receiver Propagation Delay Times** 

# TRS3222 3-V TO 5.5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH $\pm 15\text{-kV}$ ESD PROTECTION



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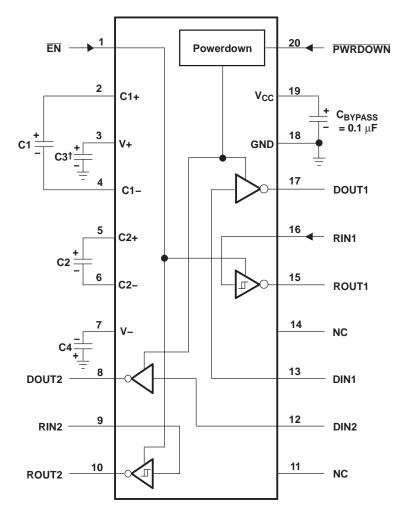




- A. C<sub>L</sub> includes probe and jig capacitance.
- B. The pulse generator has the following characteristics:  $Z_0$  = 50  $\Omega$ , 50% duty cycle,  $t_r \leq 10$  ns.  $t_f \leq 10$  ns.

Figure 4. Receiver Enable and Disable Times

#### **APPLICATION INFORMATION**



 $^{\dagger}$  C3 can be connected to V\_CC or GND.

- NOTES: A. Resistor values shown are nominal.
  - B. NC No internal connection
  - C. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V <sub>CC</sub> vs CAPACITOR VALUES						
V <sub>CC</sub>	C1	C2, C3, and C4				
3.3 V $\pm$ 0.3 V	<b>0.1</b> μ <b>F</b>	<b>0.1</b> μF				
5 V $\pm$ 0.5 V	<b>0.047</b> μ <b>F</b>	<b>0.33</b> μF				
3 V to 5.5 V	<b>0.1</b> μF	<b>0.47</b> μF				

Figure 5. Ty	vpical Operating	Circuit and	Capacitor	Values
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#### PACKAGING INFORMATION

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	Eco Plan <sup>(2)</sup>	Lead/ Ball Finish	MSL Peak Temp <sup>(3)</sup>	Samples (Requires Login)
TRS3222CDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples
TRS3222CDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	Request Free Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# PACKAGE MATERIALS INFORMATION

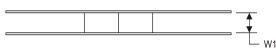
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#### TAPE AND REEL INFORMATION

#### REEL DIMENSIONS

Texas Instruments





#### TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### TAPE AND REEL INFORMATION

\*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TRS3222CDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Jul-2012



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TRS3222CDBR	SSOP	DB	20	2000	367.0	367.0	38.0

# **MECHANICAL DATA**

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

## DB (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

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